TEXAS INSTRUMENTS

CD54HC243, CD74HC243, CD54HCT243, CD74HCT243
High-Speed CMOS Logic
Quad-Bus Transceiver with Three-State Outputs

Features

- **Typical Propagation Delay (A to B, B to A) of 7ns at V_{CC} = 5V, C_L = 15pF, T_A = 25°C**
- **Three-State Outputs**
- **Buffered Inputs**
- **Fanout (Over Temperature Range)**
  - **Standard Outputs . . . . 10 LSTTL Loads**
  - **Bus Driver Outputs . . . . 15 LSTTL Loads**
- **Wide Operating Temperature Range . . . -55°C to 125°C**
- **Balanced Propagation Delay and Transition Times**
- **Significant Power Reduction Compared to LSTTL Logic ICs**
- **HC Types**
  - **2V to 6V Operation**
  - **High Noise Immunity: N_{IL} = 30%, N_{IH} = 30% of V_{CC} at V_{CC} = 5V**
- **HCT Types**
  - **4.5V to 5.5V Operation**
  - **Direct LSTTL Input Logic Compatibility, V_{IL}= 0.8V (Max), V_{IH} = 2V (Min)**
  - **CMOS Input Compatibility, $I_I \leq 1\mu A$ at V_{OL}, V_{OH}**

Pinout

**CD54HC243, CD54HCT243
(CERDIP)
CD74HC243, CD74HCT243
(PDIP, SOIC)
TOP VIEW**

```
       ___
  OEB |1    14| V_CC
   NC |2    13| OEA
   A0 |3    12| NC
   A1 |4    11| B0
   A2 |5    10| B1
   A3 |6     9| B2
  GND |7     8| B3
```

Description

The 'HC243 and 'HCT243 silicon-gate CMOS three-state bidirectional noninverting buffers are intended for two-way asynchronous communication between data buses. They have high-drive-current outputs that enable high-speed operation when driving large bus capacitances. These circuits possess the low power dissipation of CMOS circuits and have speeds comparable to low-power Schottky TTL circuits. They can drive 15 LSTTL loads.

The states of the output-enable ($\overline{OEB}$, OEA) inputs determine both the direction of flow (A to B, B to A), and the three-state mode.
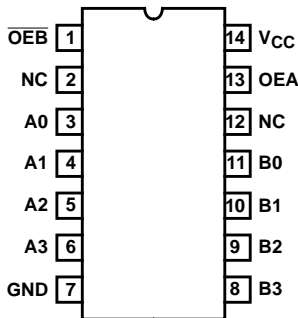
Ordering Information

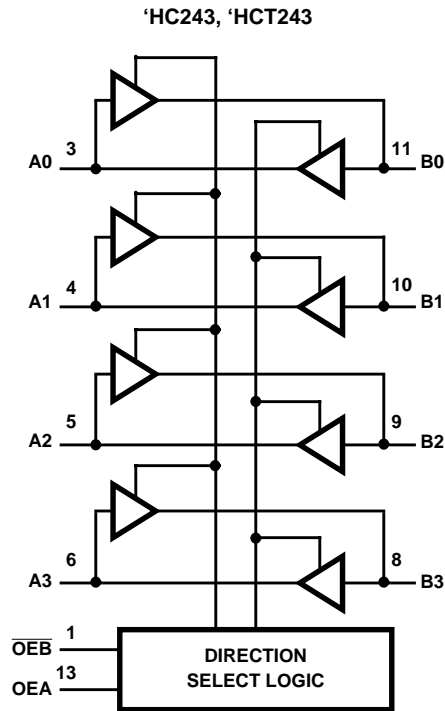| PART NUMBER	TEMP. RANGE (°C)	PACKAGE
CD54HC243F3A	-55 to 125	14 Ld CERDIP
CD54HCT243F3A	-55 to 125	14 Ld CERDIP
CD74HC243E	-55 to 125	14 Ld PDIP
CD74HC243M	-55 to 125	14 Ld SOIC
CD74HC243MT	-55 to 125	14 Ld SOIC
CD74HC243M96	-55 to 125	14 Ld SOIC
CD74HCT243E	-55 to 125	14 Ld PDIP
CD74HCT243M	-55 to 125	14 Ld SOIC

NOTE: When ordering, use the entire part number. The suffix 96 denotes tape and reel. The suffix T denotes a small-quantity reel of 250.

Functional Diagram

'HC243, 'HCT243

TRUTH TABLE

CONTROL INPUTS		HC, HCT243 SERIES	
		DATA PORT STATUS	
$\overline{\text{OEB}}$	OEA	An	Bn
H	H	O	I
L	H	Z	Z
H	L	Z	Z
L	L	I	O

H= High Voltage Level
L= Low Voltage Level
I= Input
O= Output (Same Level as Input)
Z= High Impedance
To prevent excess currents in the High Z modes all I/O terminals should be terminated with 10kΩ to 1MΩ resistors.

Absolute Maximum Ratings

DC Supply Voltage, V_{CC} . . . . -0.5V to 7V
DC Input Diode Current, I_{IK}
  For V_I < -0.5V or V_I > V_{CC} + 0.5V . . . . ±20mA
DC Output Diode Current, I_{OK}
  For V_O < -0.5V or V_O > V_{CC} + 0.5V . . . . ±20mA
DC Drain Current, per Output, I_O
  For -0.5V < V_O < V_{CC} + 0.5V . . . . ±35mA
DC Output Source or Sink Current per Output Pin, I_O
  For V_O > -0.5V or V_O < V_{CC} + 0.5V . . . . ±25mA
DC V_{CC} or Ground Current, I_{CC} . . . . ±70mA

Operating Conditions

Temperature Range (T_A) . . . . -55°C to 125°C
Supply Voltage Range, V_{CC}
  HC Types . . . . .2V to 6V
  HCT Types . . . . .4.5V to 5.5V
DC Input or Output Voltage, V_I, V_O . . . . 0V to V_{CC}
Input Rise and Fall Time
  2V . . . . 1000ns (Max)
  4.5V . . . . 500ns (Max)
  6V . . . . 400ns (Max)

Thermal Information

Thermal Resistance (Typical, Note 1) θ_{JA} (°C/W)
  E (PDIP) Package 80
  M (SOIC) Package. 86
Maximum Junction Temperature . . . . 150°C
Maximum Storage Temperature Range . . . .-65°C to 150°C
Maximum Lead Temperature (Soldering 10s) . . . . 300°C
  (SOIC - Lead Tips Only)

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

NOTE:

1. The package thermal impedance is calculated in accordance with JESD 51-7.

DC Electrical Specifications

PARAMETER	SYMBOL	TEST CONDITIONS V_I (V)	I_O (mA)	V_{CC} (V)	25°C MIN	TYP	MAX	-40°C TO 85°C MIN	MAX	-55°C TO 125°C MIN	MAX	UNITS
HC TYPES												
High Level Input Voltage	V_{IH}	-	-	2	1.5	-	-	1.5	-	1.5	-	V
				4.5	3.15	-	-	3.15	-	3.15	-	V
				6	4.2	-	-	4.2	-	4.2	-	V
Low Level Input Voltage	V_{IL}	-	-	2	-	-	0.5	-	0.5	-	0.5	V
				4.5	-	-	1.35	-	1.35	-	1.35	V
				6	-	-	1.8	-	1.8	-	1.8	V
High Level Output Voltage CMOS Loads	V_{OH}	V_{IH} or V_{IL}	-0.02	2	1.9	-	-	1.9	-	1.9	-	V
			-0.02	4.5	4.4	-	-	4.4	-	4.4	-	V
			-0.02	6	5.9	-	-	5.9	-	5.9	-	V
High Level Output Voltage TTL Loads			-6	4.5	3.98	-	-	3.84	-	3.7	-	V
			-7.8	6	5.48	-	-	5.34	-	5.2	-	V
Low Level Output Voltage CMOS Loads	V_{OL}	V_{IH} or V_{IL}	0.02	2	-	-	0.1	-	0.1	-	0.1	V
			0.02	4.5	-	-	0.1	-	0.1	-	0.1	V
			0.02	6	-	-	0.1	-	0.1	-	0.1	V
Low Level Output Voltage TTL Loads			6	4.5	-	-	0.26	-	0.33	-	0.4	V
			7.8	6	-	-	0.26	-	0.33	-	0.4	V

DC Electrical Specifications   (Continued)

PARAMETER	SYMBOL	TEST CONDITIONS		V$_{CC}$ (V)	25°C			-40°C TO 85°C		-55°C TO 125°C		UNITS
		V$_I$ (V)	I$_O$ (mA)		MIN	TYP	MAX	MIN	MAX	MIN	MAX	
Input Leakage Current	I$_I$	V$_{CC}$ or GND	-	6	-	-	±0.1	-	±1	-	±1	µA
Quiescent Device Current	I$_{CC}$	V$_{CC}$ or GND	0	6	-	-	8	-	80	-	160	µA
Three-State Leakage Current	I$_{OZ}$	V$_{IL}$ or V$_{IH}$	-	6	-	-	±0.5	-	±0.5	-	±10	µA
HCT TYPES												
High Level Input Voltage	V$_{IH}$	-	-	4.5 to 5.5	2	-	-	2	-	2	-	V
Low Level Input Voltage	V$_{IL}$	-	-	4.5 to 5.5	-	-	0.8	-	0.8	-	0.8	V
High Level Output Voltage CMOS Loads	V$_{OH}$	V$_{IH}$ or V$_{IL}$	-0.02	4.5	4.4	-	-	4.4	-	4.4	-	V
High Level Output Voltage TTL Loads			-6	4.5	3.98	-	-	3.84	-	3.7	-	V
Low Level Output Voltage CMOS Loads	V$_{OL}$	V$_{IH}$ or V$_{IL}$	0.02	4.5	-	-	0.1	-	0.1	-	0.1	V
Low Level Output Voltage TTL Loads			6	4.5	-	-	0.26	-	0.33	-	0.4	V
Input Leakage Current	I$_I$	V$_{CC}$ to GND	-	5.5	-	-	±0.1	-	±1	-	±1	µA
Quiescent Device Current	I$_{CC}$	V$_{CC}$ or GND	0	5.5	-	-	8	-	80	-	160	µA
Additional Quiescent Device Current Per Input Pin: 1 Unit Load	ΔI$_{CC}$ (Note 2)	V$_{CC}$ -2.1	-	4.5 to 5.5	-	100	360	-	450	-	490	µA
Three-State Leakage Current	I$_{OZ}$	V$_{IL}$ or V$_{IH}$	-	5.5	-	-	±0.5	-	±5.0	-	±10	µA

NOTE:

2. For dual-supply systems theoretical worst case (V$_I$ = 2.4V, V$_{CC}$ = 5.5V) specification is 1.8mA.

HCT Input Loading Table

INPUT	UNIT LOADS
An, Bn	1.1
OEA, $\overline{OEB}$	0.6

NOTE: Unit Load is ΔI$_{CC}$ limit specified in DC Electrical Specifications table, e.g., 360µA max at 25°C.

CD54HC243, CD74HC243, CD54HCT243, CD74HCT243

Switching Specifications Input t_r, t_f = 6ns

PARAMETER	SYMBOL	TEST CONDITIONS	V_{CC} (V)	25°C TYP	25°C MAX	-40°C TO 85°C MAX	-55°C TO 125°C MAX	UNITS
HC TYPES								
Propagation Delay Data to Outputs	t_{PLH}, t_{PHL}	C_L = 50pF	2	-	90	115	135	ns
			4.5	-	18	23	27	ns
		C_L = 15pF	5	7	-	-	-	ns
		CL = 50pF	6	-	15	20	23	ns
Output High-Z, to High Level to Low Level	t_{PZL}, t_{PZH}	C_L = 50pF	2	-	150	190	225	ns
		CL = 50pF	4.5	-	30	38	45	ns
		CL = 15pF	5	12	-	-	-	ns
		CL = 50pF	6	-	26	33	38	ns
Output High Level, Output Low Level to High-Z	t_{PHZ}, t_{PLZ}	C_L = 50pF	2	-	150	190	225	ns
		CL = 50pF	4.5	-	30	38	45	ns
		CL = 15pF	5	12	-	-	-	ns
		CL = 50pF	6	-	26	33	38	ns
Output Transition Times	t_{TLH}, t_{THL}	C_L = 50pF	2	-	60	75	90	ns
			4.5	-	12	15	18	ns
			6	-	10	13	15	ns
Input Capacitance	C_I	-	-	-	10	10	10	pF
Three-State Output Capacitance	C_O	-	-	-	20	20	20	pF
Power Dissipation Capacitance (Notes 3, 4)	C_{PD}	-	5	80	-	-	-	pF
HCT TYPES								
Propagation Delay Data to Outputs	t_{PLH}, t_{PHL}	C_L = 50pF	4.5	-	22	28	33	ns
		C_L = 15pF	5	9	-	-	-	ns
Output High-Z to High Level to Low Level	t_{PZH}, t_{PZL}	C_L = 50pF	4.5	-	34	43	51	ns
		C_L = 15pF	5	14	-	-	-	ns
Output High Level, Output Low Level to High-Z	t_{PHZ}, t_{PLZ}	C_L = 50pF	4.5	-	35	44	53	ns
		C_L = 15pF	5	14	-	-	-	ns
Output Transition Times	t_{TLH}, t_{THL}	C_L = 50pF	4.5	-	12	15	18	ns
Input Capacitance	C_I	-	-	-	10	10	10	pF
Three-State Output Capacitance	C_O	-	-	-	20	20	20	pF
Power Dissipation Capacitance (Notes 3, 4)	C_{PD}	-	5	91	-	-	-	pF

NOTES:

3. C_{PD} is used to determine the dynamic power consumption, per channel.

4. $P_D = V_{CC}^2 f_i (C_{PD} + C_L)$ where f_i = Input Frequency, f_O = Output Frequency, C_L = Output Load Capacitance, V_{CC} = Supply Voltage.

Test Circuits and Waveforms

FIGURE 1. HC AND HCT TRANSITION TIMES AND PROPAGA-TION DELAY TIMES, COMBINATION LOGIC
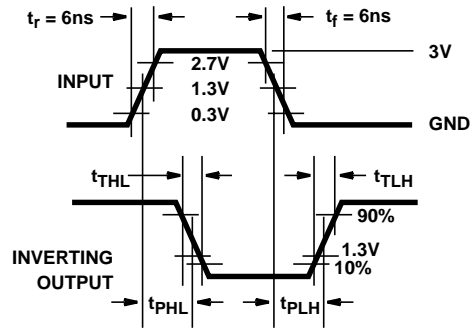
FIGURE 2. HCT TRANSITION TIMES AND PROPAGATION DELAY TIMES, COMBINATION LOGIC
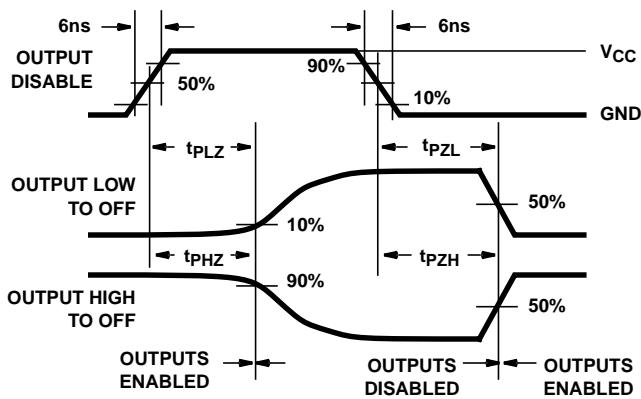

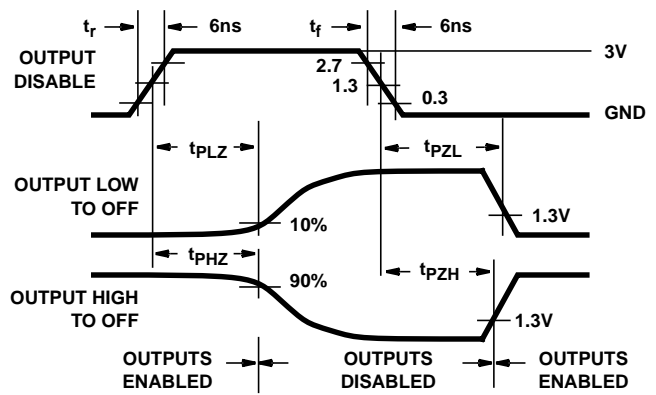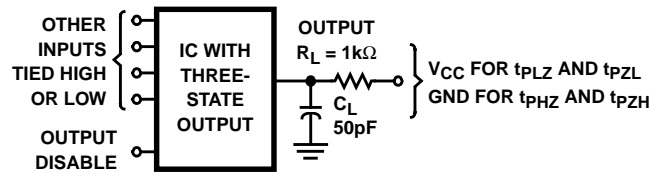**FIGURE 3. HC THREE-STATE PROPAGATION DELAY WAVEFORM**

FIGURE 4. HCT THREE-STATE PROPAGATION DELAY WAVEFORM

NOTE: Open drain waveforms t_{PLZ} and t_{PZL} are the same as those for three-state shown on the left. The test circuit is Output R_L = 1kΩ to V_{CC}, C_L = 50pF.

FIGURE 5. HC AND HCT THREE-STATE PROPAGATION DELAY TEST CIRCUIT

PACKAGE OPTION ADDENDUM

PACKAGING INFORMATION

Orderable Device	Status [1]	Package Type	Package Drawing	Pins	Package Qty	Eco Plan [2]	Lead/Ball Finish	MSL Peak Temp [3]
8409001CA	ACTIVE	CDIP	J	14	1	TBD	A42	N / A for Pkg Type
CD54HC243F	ACTIVE	CDIP	J	14	1	TBD	A42	N / A for Pkg Type
CD54HC243F3A	ACTIVE	CDIP	J	14	1	TBD	A42	N / A for Pkg Type
CD54HCT243F3A	ACTIVE	CDIP	J	14	1	TBD	A42	N / A for Pkg Type
CD74HC243E	ACTIVE	PDIP	N	14	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
CD74HC243EE4	ACTIVE	PDIP	N	14	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
CD74HC243M	ACTIVE	SOIC	D	14	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HC243M96	ACTIVE	SOIC	D	14	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HC243M96E4	ACTIVE	SOIC	D	14	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HC243M96G4	ACTIVE	SOIC	D	14	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HC243ME4	ACTIVE	SOIC	D	14	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HC243MG4	ACTIVE	SOIC	D	14	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HC243MT	ACTIVE	SOIC	D	14	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HC243MTE4	ACTIVE	SOIC	D	14	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HC243MTG4	ACTIVE	SOIC	D	14	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HCT243E	ACTIVE	PDIP	N	14	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
CD74HCT243EE4	ACTIVE	PDIP	N	14	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
CD74HCT243M	ACTIVE	SOIC	D	14	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HCT243ME4	ACTIVE	SOIC	D	14	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HCT243MG4	ACTIVE	SOIC	D	14	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM

[1] The marketing status values are defined as follows:
ACTIVE: Product device recommended for new designs.
LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.
NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.
PREVIEW: Device has been announced but is not in production. Samples may or may not be available.
OBSOLETE: TI has discontinued the production of the device.

[2] Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.
TBD: The Pb-Free/Green conversion plan has not been defined.
Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

[3] MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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PACKAGE MATERIALS INFORMATION

TAPE AND REEL INFORMATION

REEL DIMENSIONS

TAPE DIMENSIONS

A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE

*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CD74HC243M96	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
CD74HC243MT	SOIC	D	14	250	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1

TAPE AND REEL BOX DIMENSIONS

*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
CD74HC243M96	SOIC	D	14	2500	346.0	346.0	33.0
CD74HC243MT	SOIC	D	14	250	346.0	346.0	33.0

DIM \ PINS **	14	16	18	20
[A]	0.300 (7,62) BSC	0.300 (7,62) BSC	0.300 (7,62) BSC	0.300 (7,62) BSC
B MAX	0.785 (19,94)	.840 (21,34)	0.960 (24,38)	1.060 (26,92)
B MIN	—	—	—	—
C MAX	0.300 (7,62)	0.300 (7,62)	0.310 (7,87)	0.300 (7,62)
C MIN	0.245 (6,22)	0.245 (6,22)	0.220 (5,59)	0.245 (6,22)

B

14   8

1   7

0.065 (1,65)
0.045 (1,14)

C

0.005 (0,13) MIN

0.060 (1,52)
0.015 (0,38)

0.200 (5,08) MAX

Seating Plane

0.130 (3,30) MIN

0.026 (0,66)
0.014 (0,36)

0.100 (2,54)

[A]

0°-15°

0.014 (0,36)
0.008 (0,20)

4040083/F 03/03

NOTES: A. All linear dimensions are in inches (millimeters).
          B. This drawing is subject to change without notice.
          C. This package is hermetically sealed with a ceramic lid using glass frit.
          D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
          E. Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.

N (R–PDIP–T**)
16 PINS SHOWN

PLASTIC DUAL–IN–LINE PACKAGE

DIM \ PINS **	14	16	18	20
A MAX	0.775 (19,69)	0.775 (19,69)	0.920 (23,37)	1.060 (26,92)
A MIN	0.745 (18,92)	0.745 (18,92)	0.850 (21,59)	0.940 (23,88)
MS–001 VARIATION	AA	BB	AC	AD

0.260 (6,60) / 0.240 (6,10)

A

16   9

1   8

0.070 (1,78) / 0.045 (1,14) ⚠D

0.045 (1,14) / 0.030 (0,76) ⚠D

0.020 (0,51) MIN

0.200 (5,08) MAX

Seating Plane

0.125 (3,18) MIN

0.100 (2,54)

0.021 (0,53) / 0.015 (0,38)

⊕ 0.010 (0,25) Ⓜ

14/18 Pin Only
20 Pin vendor option ⚠D

0.325 (8,26) / 0.300 (7,62)

0.015 (0,38)

Gauge Plane

0.010 (0,25) NOM

0.430 (10,92) MAX

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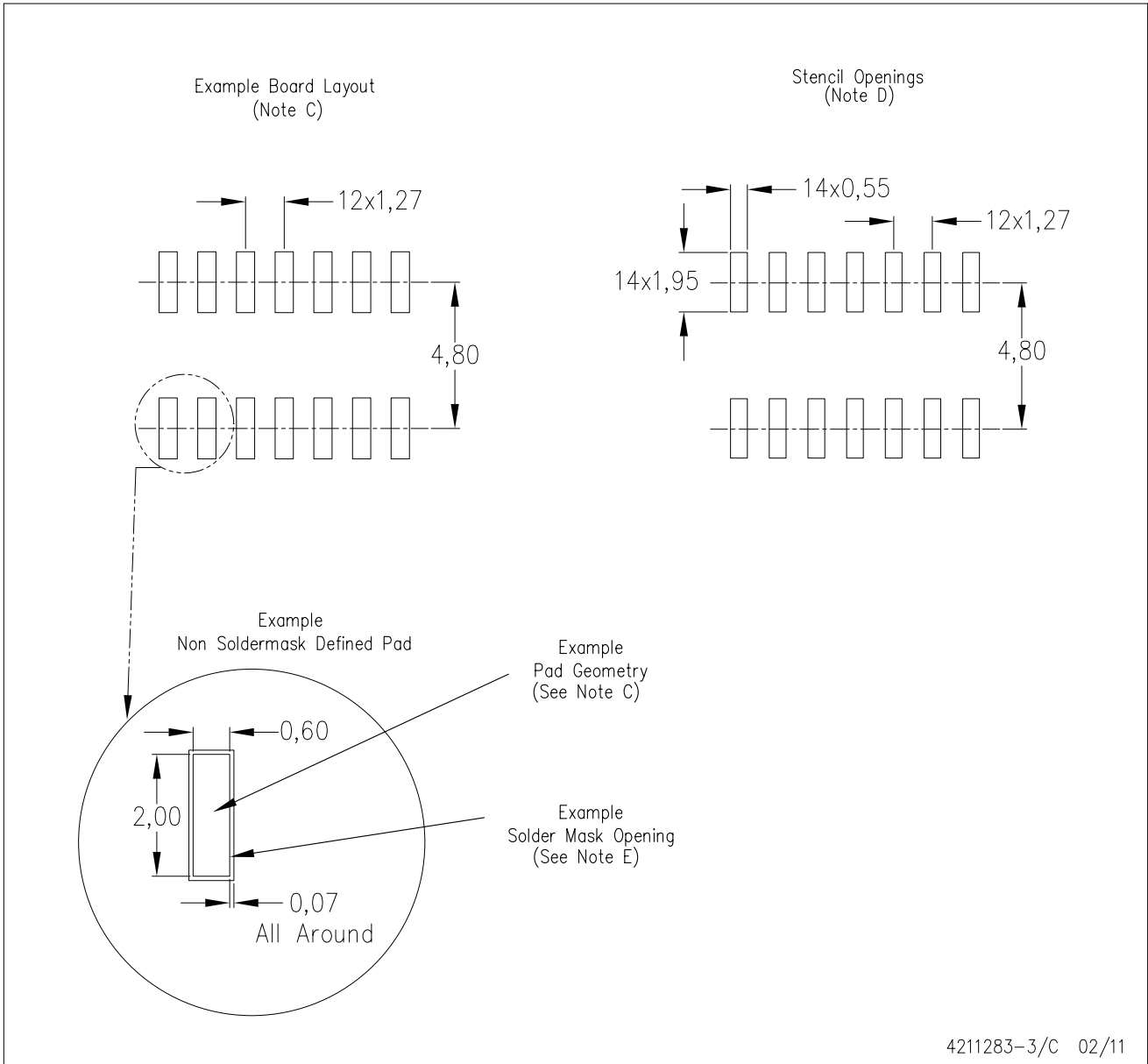
NOTES: A. All linear dimensions are in inches (millimeters).
         B. This drawing is subject to change without notice.
   ⚠C   Falls within JEDEC MS–001, except 18 and 20 pin minimum body length (Dim A).
   ⚠D   The 20 pin end lead shoulder width is a vendor option, either half or full width.

TEXAS
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D (R−PDSO−G14)   PLASTIC SMALL OUTLINE

$$\frac{0.344\ (8,75)}{0.337\ (8,55)}$$

△C

14   8

$$\frac{0.244\ (6,20)}{0.228\ (5,80)}$$

$$\frac{0.157\ (4,00)}{0.150\ (3,80)}$$ △D

Pin 1
Index Area

1   7

0.050 (1,27)

$$\frac{0.020\ (0,51)}{0.012\ (0,31)}$$

⊕ | 0.010 (0,25) Ⓜ

0.069 (1,75) Max

$$\frac{0.010\ (0,25)}{0.004\ (0,10)}$$

$$\frac{0.010\ (0,25)}{0.005\ (0,13)}$$

0.004 (0,10)

Gauge Plane

Seating Plane

0.010 (0,25)   0°–8°

$$\frac{0.050\ (1,27)}{0.016\ (0,40)}$$

4040047−4/L   02/11

NOTES: A.   All linear dimensions are in inches (millimeters).
         B.   This drawing is subject to change without notice.
       △C   Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall
              not exceed 0.006 (0,15) each side.
       △D   Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
         E.   Reference JEDEC MS−012 variation AB.

D (R−PDSO−G14)   PLASTIC SMALL OUTLINE

Example Board Layout
(Note C)

Stencil Openings
(Note D)

12x1,27

14x0,55

12x1,27

14x1,95

4,80

4,80

Example
Non Soldermask Defined Pad

Example
Pad Geometry
(See Note C)

0,60

2,00

Example
Solder Mask Opening
(See Note E)

0,07
All Around

4211283−3/C 02/11

NOTES: A. All linear dimensions are in millimeters.
         B. This drawing is subject to change without notice.
         C. Publication IPC−7351 is recommended for alternate designs.
         D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should
             contact their board assembly site for stencil design recommendations. Refer to IPC−7525 for other stencil recommendations.
         E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.

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